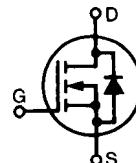


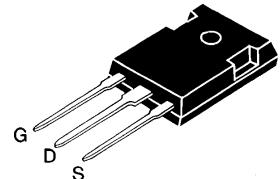
# HiPerFET™ Power MOSFETs

N-Channel Enhancement Mode  
High dv/dt, Low  $t_{rr}$ , HDMOS™ Family

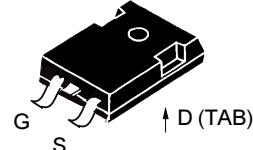
	$V_{DSS}$	$I_{D25}$	$R_{DS(on)}$	$t_{rr}$
<b>IXFH8N80</b>	800V	8A	1.1Ω	250 ns
<b>IXFH9N80</b>	800V	9A	0.9Ω	250 ns



TO-247 AD (IXFH)



TO-247 SMD\*



Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	800	V	
$V_{DGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GS} = 1 \text{ M}\Omega$	800	V	
$V_{GS}$	Continuous	$\pm 20$	V	
$V_{GSM}$	Transient	$\pm 30$	V	
$I_{D25}$	$T_c = 25^\circ\text{C}$	8N80 9N80	8 9	A
$I_{DM}$	$T_c = 25^\circ\text{C}$ , pulse width limited by $T_{JM}$	8N80 9N80	32 36	A
$I_{AR}$	$T_c = 25^\circ\text{C}$	8N80 9N80	8 9	A
$E_{AR}$	$T_c = 25^\circ\text{C}$	18	mJ	
$dv/dt$	$I_s \leq I_{DM}$ , $di/dt \leq 100 \text{ A}/\mu\text{s}$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ\text{C}$ , $R_G = 2 \Omega$	5	V/ns	
$P_D$	$T_c = 25^\circ\text{C}$	180	W	
$T_J$		-55 ... +150	°C	
$T_{JM}$		150	°C	
$T_{stg}$		-55 ... +150	°C	
$M_d$	Mounting torque	1.13/10 Nm/lb.in.		
Weight		TO-204 = 18 g, TO-247 = 6 g		
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s		300	°C	

Symbol	Test Conditions	Characteristic Values		
		( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$V_{DSS}$	$V_{GS} = 0 \text{ V}$ , $I_D = 3 \text{ mA}$ $V_{DSS}$ temperature coefficient	800 0.088		V %/K
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 2.5 \text{ mA}$ $V_{GS(th)}$ temperature coefficient	2 -0.257	4.5 %/K	V %/K
$I_{GSS}$	$V_{GS} = \pm 20 \text{ V}_{DC}$ , $V_{DS} = 0$		$\pm 100$	nA
$I_{DSS}$	$V_{DS} = 0.8 \cdot V_{DSS}$ $V_{GS} = 0 \text{ V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	250 1	$\mu\text{A}$ mA
$R_{DS(on)}$	$V_{GS} = 10 \text{ V}$ , $I_D = 0.5 \cdot I_{D25}$ Pulse test, $t \leq 300 \mu\text{s}$ , duty cycle $\delta \leq 2\%$	8N80 9N80	1.1 0.9	Ω Ω

## Features

- International standard packages
- Low  $R_{DS(on)}$  HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect
- Fast intrinsic Rectifier

## Applications

- DC-DC converters
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls

## Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- Space savings
- High power density



Figure 1. Output Characteristics at 25°C

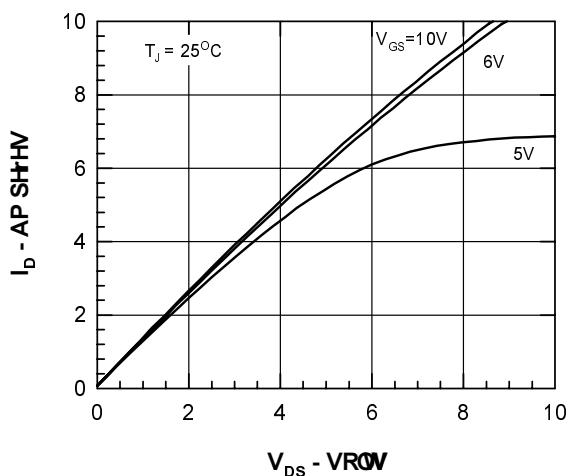


Figure 2. Output Characteristics at 125°C

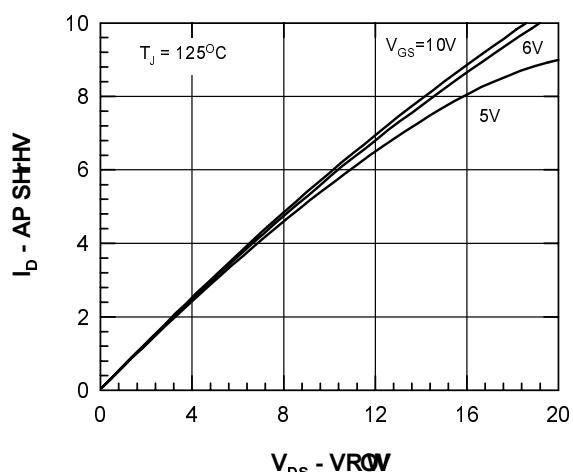


Figure 3.  $R_{DS(on)}$  normalized to 15A/25°C vs.  $I_D$

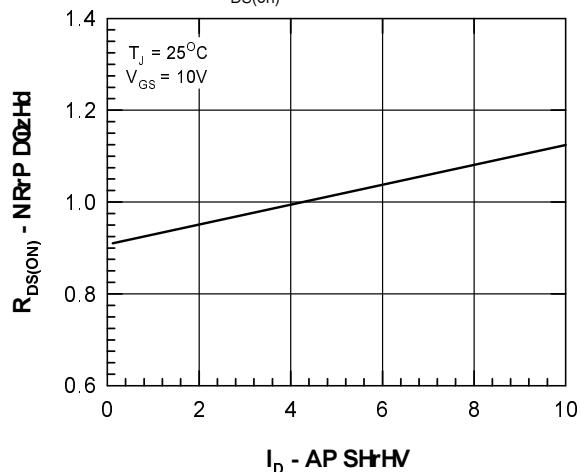


Figure 4.  $R_{DS(on)}$  normalized to 15A/25°C vs.  $T_J$

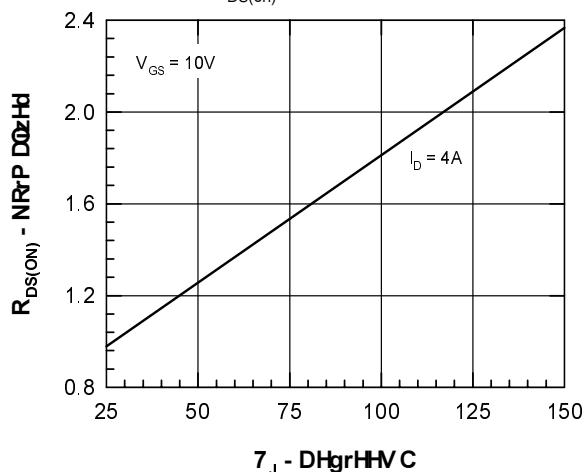


Figure 5. Drain Current vs. Case Temperature

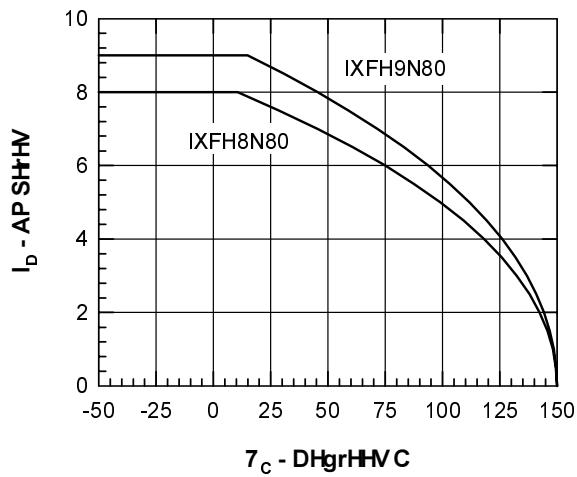


Figure 6. Admittance Curves

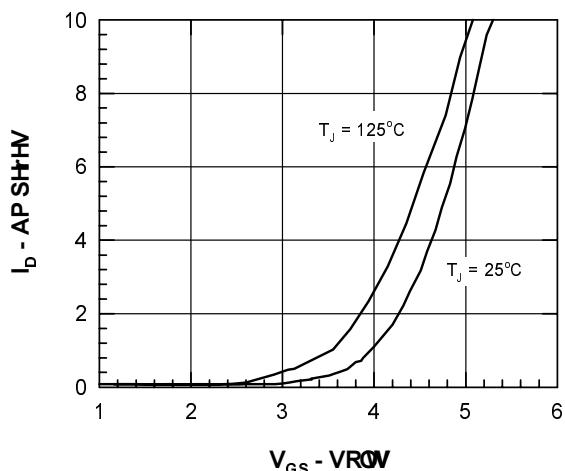


Figure 7. Gate Charge

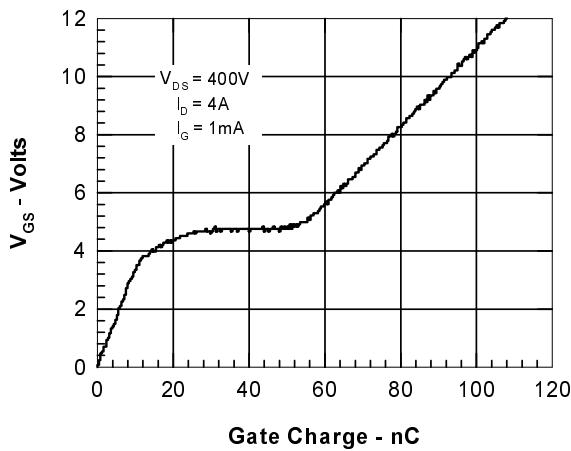


Figure 8. Capacitance Curves

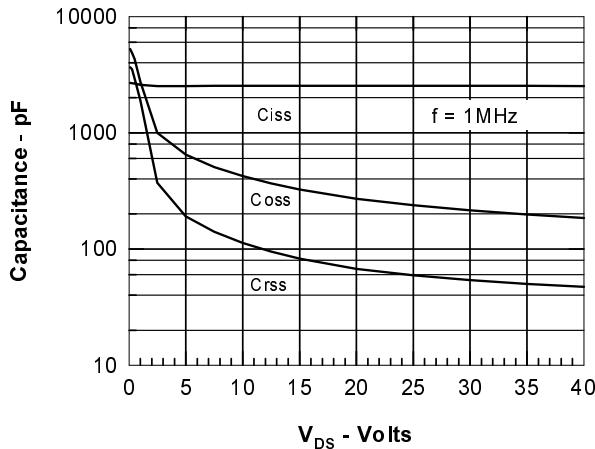


Figure 9. Forward Voltage Drop of the Intrinsic Diode

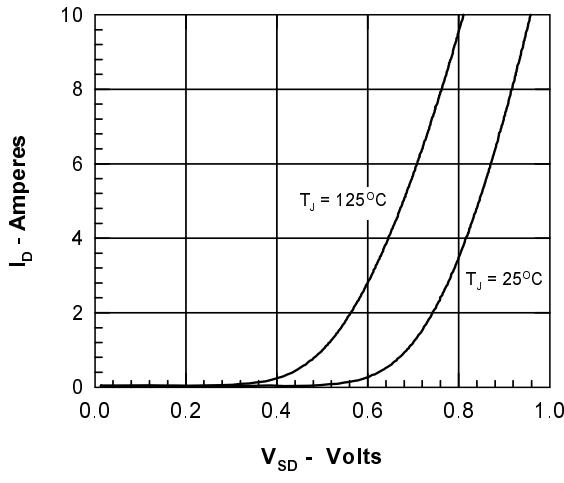


Figure 10. Forward Bias Safe Operating Area

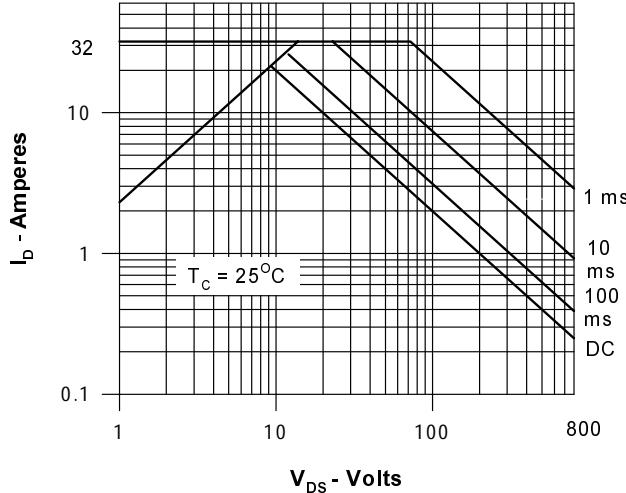
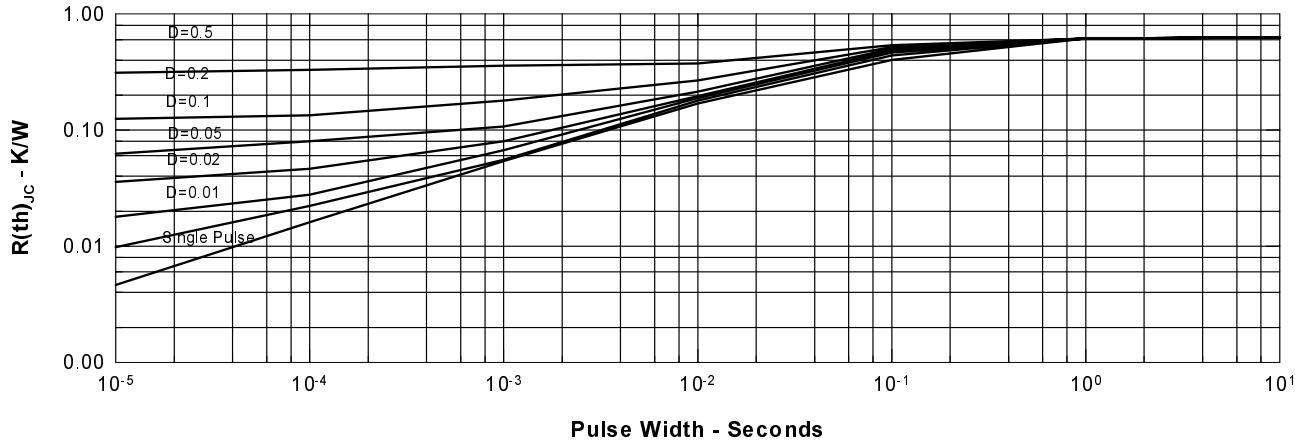


Figure 11. Transient Thermal Resistance



IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715  
4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025



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